WAS4736 MIC/GND Cross-point Switch for CITA and OMTP Mobile Audio Key Application

Descriptions

The WAS4736 is an audio jack detection switch for CITA and OMTP 4-pole accessories. The pin MIC is on audio key side, as WAS4736' O1/O2 is plugged into audio jack of cell phone, it will detect the locations of ground (GND) and microphone (MIC) poles on the audio plug and automatically routes them to the appropriate connections.

The MIC switch' Ron is 5Ω (typical) while the Ground switch has a low Ron of 0.5 Ω (typical) to minimize voltage drop across it, preventing undesired increase in ground reference voltage.

As VCC is power-up, WAS4736 is enabled and it consumes ultra-low quiescent current, less than 600nA (typical). The range of signal swing in transmission can be rail-to-rail (0~VCC), even WAS4736 can tolerate signal swing higher than VCC but less than VCC+3V with very little inverse leakage into VCC supply and not any damage of the device. The speed of signal is recommended not more than 300KHz.

The WAS4736 is available in SOT-353 package. Standard product is Pb-Free and halogen-Free.

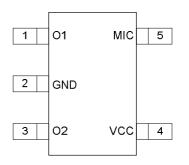
Features

- Supply voltage range : 2.3 ~ 5.5V
- Detects polarity of GND and MIC on 4-pole plugs
- Automatically routes GND and MIC to audio jack terminals
- low R_{DSON} for MIC Switch (5 Ω) and GND switch (0.5 Ω)
- Ultra-Low quiescent current, < 600nA (typical)
- ESD Rating (MIL-STD-883J / Method 3015.8)
 - ♦ IO to GND : ±8KV
 - Power to GND : ±8KV

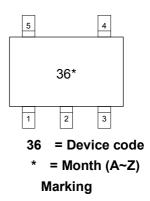




SOT-353(SC70-5)



Pin configuration (Top view)



Order information

Device	Package	Shipping
WAS4736B-5/TR	SOT-353	3000/Reel&Tape

Applications

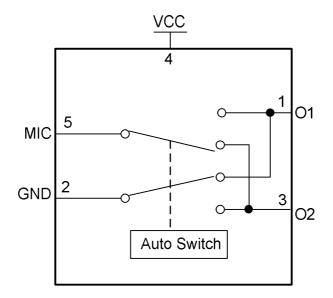
Mobile Audio Key



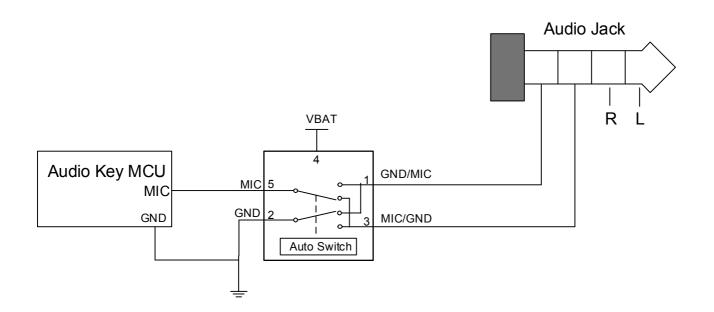
Pin descriptions

Pin Number	Symbol	Descriptions	
1	01	Output One that connects to pole 4(or 3) of Audio Jack	
2	GND	Ground	
3	O2	Output Two that connects to pole 3(or 4) of Audio Jack	
4	VCC	Power Supply that supports $2.3v \sim 5.5v$	
5	MIC	MIC input from Audio Key	

Functional Block



Typical Applications





Absolute Maximum Ratings ⁽¹⁾

Parameter			Symbol	Value	Unit
Suppl	y Voltage		Vcc	-0.3 ~ 6.5	V
Contro	ol Input Voltage		VINx	-0.3 ~ 6.5	V
DC In	put Voltage ⁽²⁾		VINPUT	-0.3 ~ 6.5	V
Contir	nuous Current through COMx			±100	mA
Storage Temperature Range			Tstg	-65 ~ 150	°C
Junction Temperature under Bias			TJ	150	°C
Lead Temperature (Soldering, 10 seconds)			T∟	260	°C
Power	Power Dissipation			250	mW
	I ID to GND			±8	KV
HBM (MIL-STD-883H/Method 3015.8)		Power to GND		±8	KV
E3D	MM (JESD22-A115)	IO to GND		±900	V
		Power to GND		±900	V

Recommend operating ratings ⁽³⁾

Parameter	Symbol	Value	Unit
Supply Voltage Operating	Vcc	2.3 ~ 5.5	V
Control Input Voltage	VIN	0.0 ~ V _{CC}	V
Input Signal Voltage	Vis	0.0 ~ V _{CC}	V
Operating Temperature	TA	-40 ~ 85	°C
Input Raise and Fall Time(Control Input Vcc=2.3~5.5V)	tr,tf	0 ~ 10	ns/V
Thermal Resistance	R _{0JA}	350	°C/W

Note:

- 1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.



DC Electronics Characteristics (Ta=25°C, VCC=3.6V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply quiescent current	Icc	VCC is power-up		600		nA
GND path On-Resistance	Ron-gnd			0.5		Ω
MIC path On-Resistance	Ron-міс			5		Ω

AC Electronics Characteristics (Ta=25°C, VCC=3.6V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
MIC path -3dB Bandwidth	BW	MIC Bias=1.8V		50		MHz
MIC path-Sub Bahuwiuth	DVV	MIC pull-up resistor =2K		50		

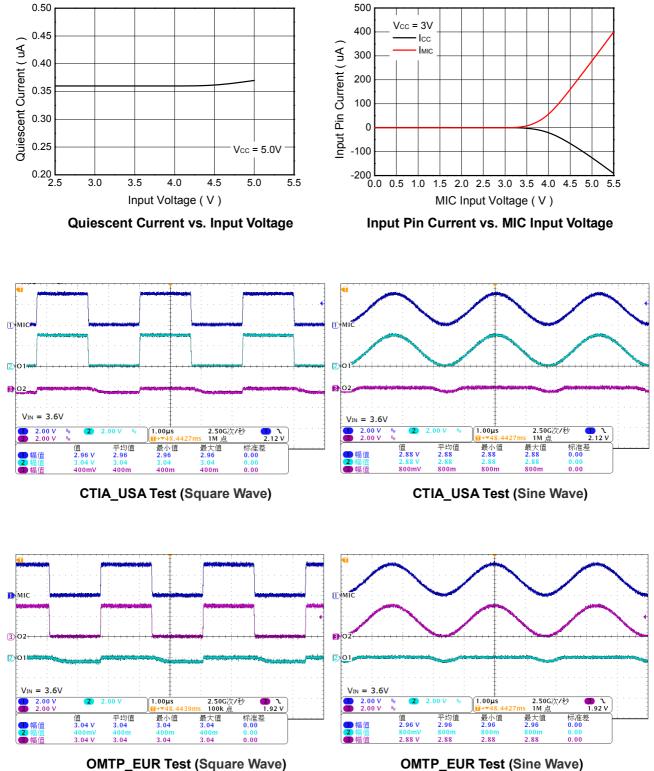
(Not tested but guaranteed by design)

Capacitance (Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Off capacitance	Coff	F=100KHz, VCC=3.3		100		pF
On capacitance	Con	F=100KHz, VCC=3.3		140		pF



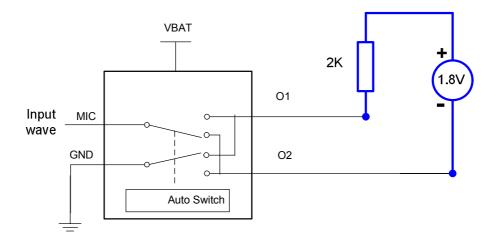
Typical Characteristics (Ta=25°C, unless otherwise noted)



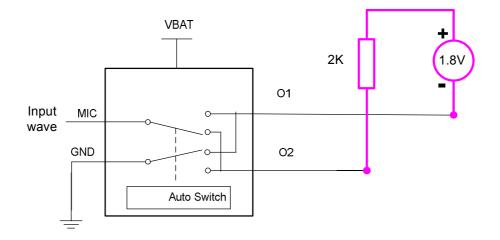
OMTP_EUR Test (Sine Wave)

III SEMI

Test Circuit





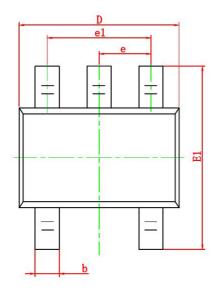


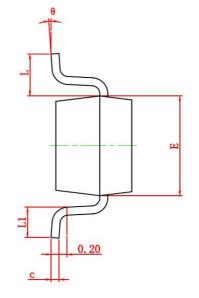
OMTP_EUR Test Circuits

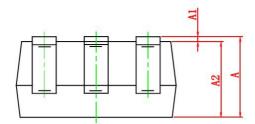
🖊 SEMI

Package Information









Symbol	Dimensions In Millimeters				
Symbol	Min.	Max.			
A	0.900	1.100			
A1	0.000	0.100			
A2	0.900	1.000			
b	0.150	0.350			
С	0.080	0.150			
D	2.000	2.200			
E	1.150	1.350			
E1	2.150	2.450			
е	0.650 Typ.				
e1	1.2	1.4			
L	0.525 Ref.				
L1	0.260	0.460			
θ	0° 8°				